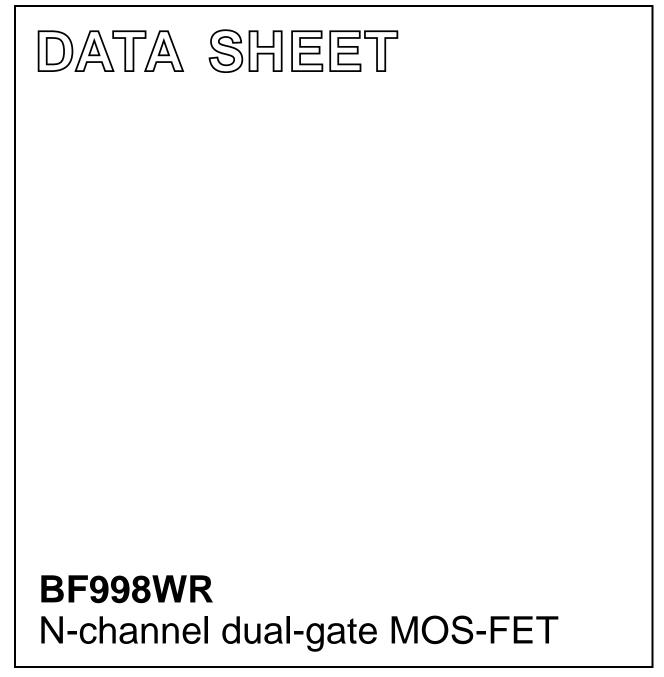
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1995 Apr 25 1997 Sep 05



#### FEATURES

- High forward transfer admittance
- Short channel transistor with high forward transfer admittance to input capacitance ratio
- Low noise gain controlled amplifier up to 1 GHz.

#### APPLICATIONS

• VHF and UHF applications with 12 V supply voltage, such as television tuners and professional communications equipment.

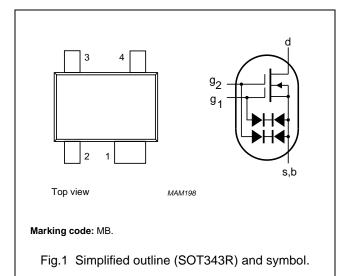
#### DESCRIPTION

Depletion type field-effect transistor in a plastic microminiature SOT343R package with source and substrate interconnected. The transistor is protected against excessive input voltage surges by integrated back-to-back diodes between gates and source.

#### CAUTION

The device is supplied in an antistatic package. The gate-source input must be protected against static discharge during transport or handling.

PINNING					
PIN	SYMBOL	DESCRIPTION			
1	s, b	source			
2	d	drain			
3	<b>g</b> 2	gate 2			
4	g1	gate 1			



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>DS</sub>	drain-source voltage		-	_	12	V
I <sub>D</sub>	drain current		_	_	30	mA
P <sub>tot</sub>	total power dissipation		_	_	300	mW
Tj	operating junction temperature		_	_	150	°C
y <sub>fs</sub>	forward transfer admittance		_	24	_	mS
C <sub>ig1-s</sub>	input capacitance at gate 1		_	2.1	_	pF
C <sub>rs</sub>	reverse transfer capacitance	f = 1 MHz	_	25	-	fF
F	noise figure	f = 800 MHz	-	1	<b> </b> _	dB

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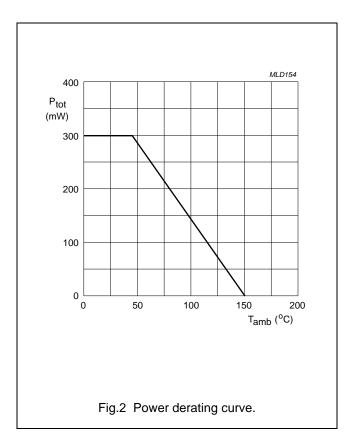
#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>DS</sub>	drain-source voltage		_	12	V
I <sub>D</sub>	drain current		_	30	mA
I <sub>G1</sub>	gate 1 current		-	±10	mA
I <sub>G2</sub>	gate 2 current		-	±10	mA
P <sub>tot</sub>	total power dissipation	up to $T_{amb} = 45 \text{ °C}$ ; see Fig.2; note 1	_	300	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	operating junction temperature		-	+150	°C

#### Note

1. Device mounted on a printed-circuit board.



## BF998WR

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	350	K/W
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	note 2; T <sub>s</sub> = 90 °C	200	K/W

#### Notes

- 1. Device mounted on a printed-circuit board.
- 2.  $T_s$  is the temperature at the soldering point of the source lead.

#### STATIC CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>(BR)G1-SS</sub>	gate 1-source breakdown voltage	$V_{G2-S} = V_{DS} = 0; I_{G1-S} = 10 \text{ mA}$	6	20	V
V <sub>(BR)G2-SS</sub>	gate 2-source breakdown voltage	$V_{G1-S} = V_{DS} = 0$ ; $I_{G2-S} = 10 \text{ mA}$	6	20	V
V <sub>(P)G1-S</sub>	gate 1-source cut-off voltage	$V_{G2-S}$ = 4 V; $V_{DS}$ = 8 V; $I_D$ = 20 $\mu$ A	-	-2.5	V
V <sub>(P)G2-S</sub>	gate 2-source cut-off voltage	$V_{G1-S} = 0; V_{DS} = 8 V; I_D = 20 \ \mu A$	-	-2	V
I <sub>DSS</sub>	drain-source current	$V_{G2-S} = 4 V; V_{DS} = 8 V; V_{G1-S} = 0$	2	18	mA
I <sub>G1-SS</sub>	gate 1 cut-off current	$V_{G2-S} = V_{DS} = 0; V_{G1-S} = 5 V$	-	50	nA
I <sub>G2-SS</sub>	gate 2 cut-off current	$V_{G1-S} = V_{DS} = 0; V_{G2-S} = 5 V$	-	50	nA

#### **DYNAMIC CHARACTERISTICS**

Common source;  $T_{amb}$  = 25 °C;  $V_{G2-S}$  = 4 V;  $I_D$  = 10 mA;  $V_{DS}$  = 8 V; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
y <sub>fs</sub>	forward transfer admittance	pulsed; T <sub>j</sub> = 25 °C	22	25	-	mS
C <sub>ig1-s</sub>	input capacitance at gate 1	f = 1 MHz	_	2.1	2.5	pF
C <sub>ig2-s</sub>	input capacitance at gate 2	f = 1 MHz	-	1.2	-	pF
C <sub>os</sub>	drain-source capacitance	f = 1 MHz	-	1.05	-	pF
C <sub>rs</sub>	reverse transfer capacitance	f = 1 MHz	_	25	-	fF
F	noise figure	$f = 200 \text{ MHz}; G_S = 2 \text{ mS}; B_S = B_{Sopt}$	_	0.6	-	dB
		f = 800 MHz; $G_S$ = 3.3 mS; $B_S$ = $B_{Sopt}$	-	1	-	dB

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0.4 V

0.3 V

0.2 V 0.1 V 0 V

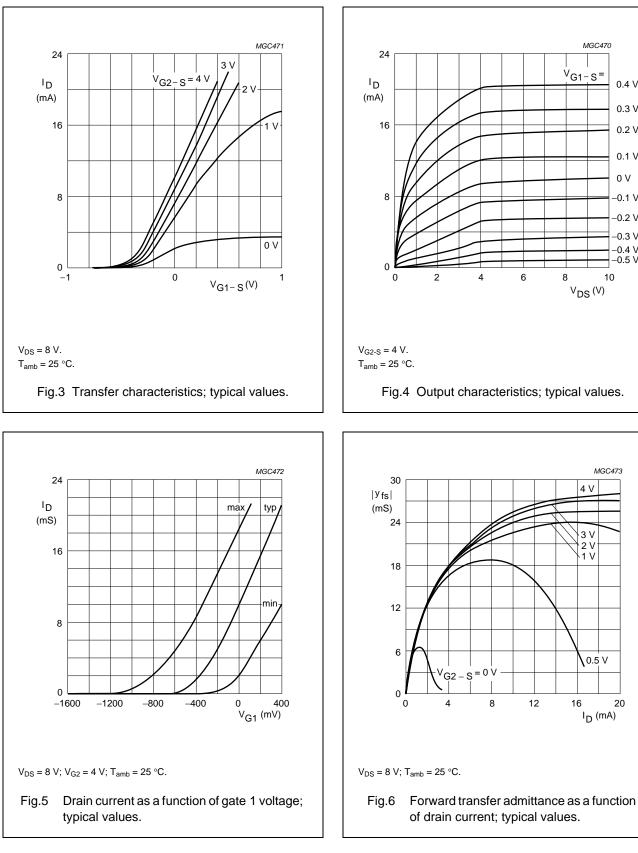
–0.1 V –0.2 V –0.3 V

–0.4 V –0.5 V

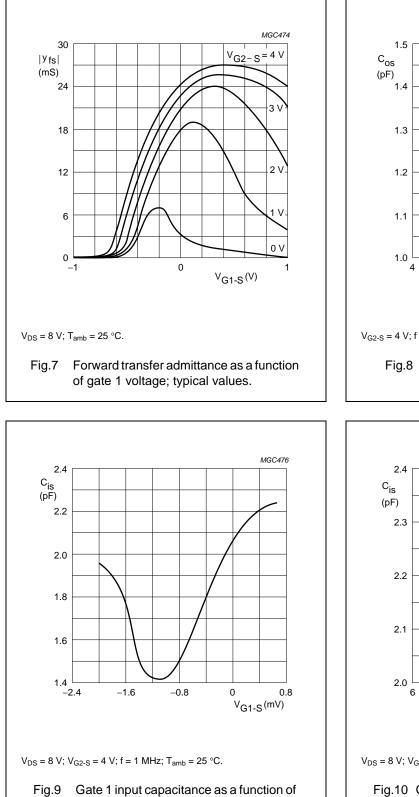
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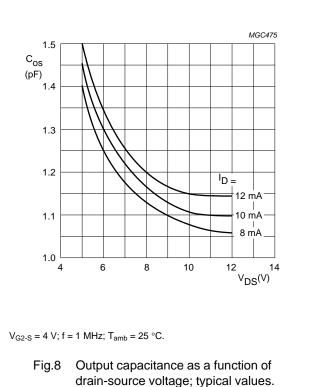
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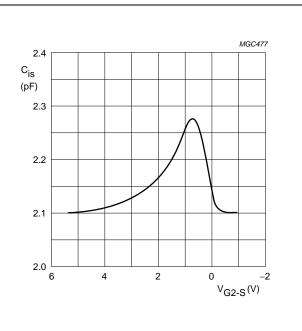


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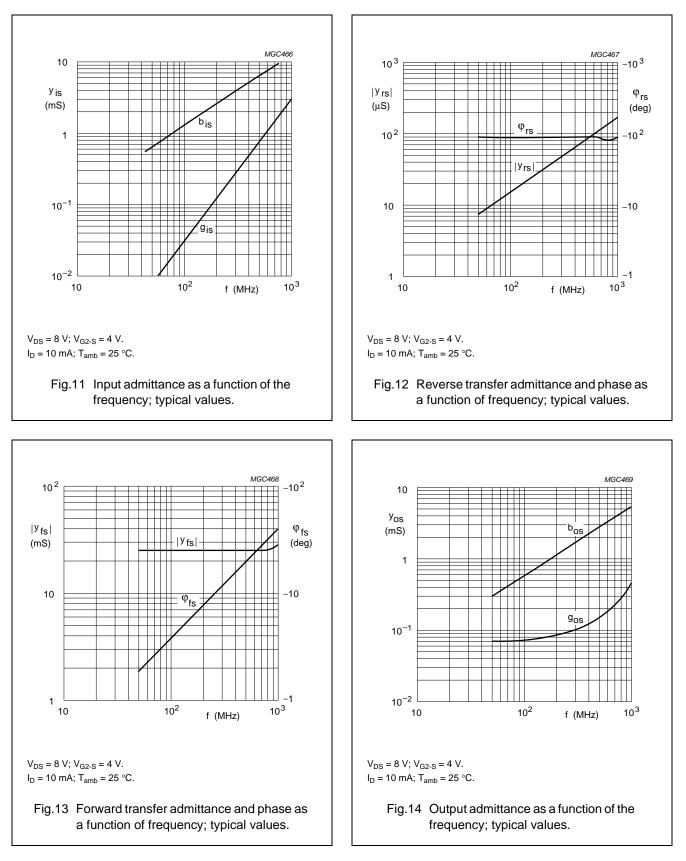
gate 1-source voltage; typical values.

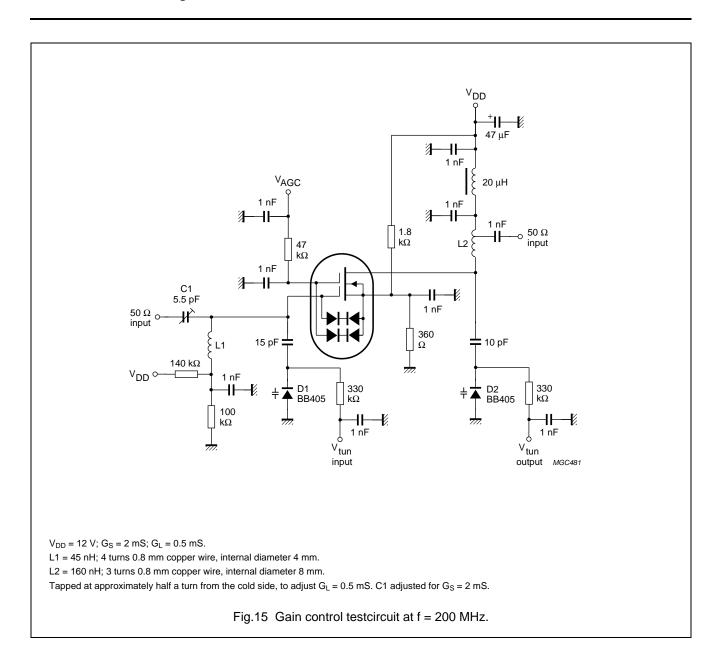


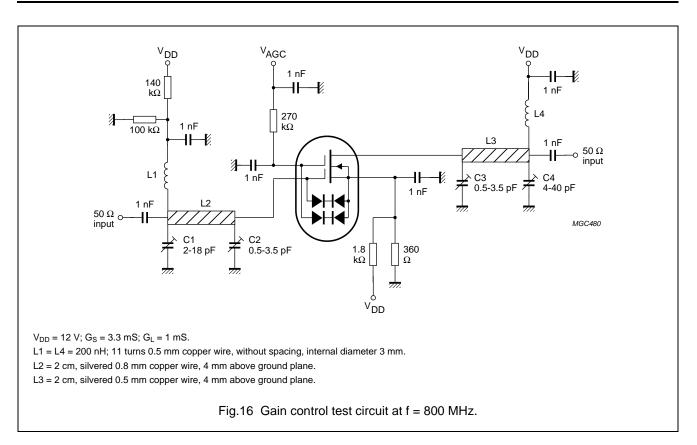


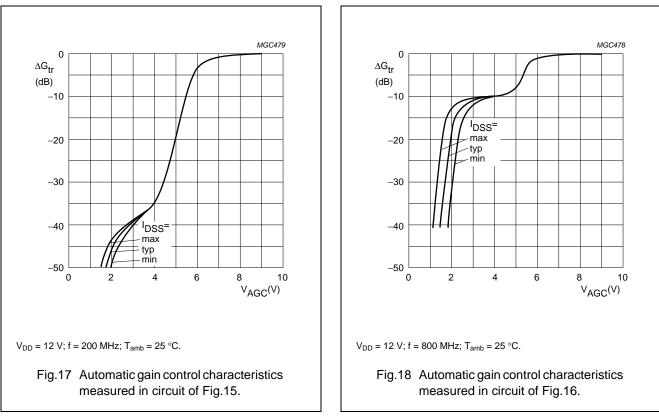
 $V_{DS} = 8 \text{ V}; \text{ } V_{G1\text{-}S} = 0 \text{ } \text{V}; \text{ } \text{f} = 1 \text{ } \text{MHz}; \text{ } \text{T}_{amb} = 25 \text{ }^{\circ}\text{C}.$ 

Fig.10 Gate 1 input capacitance as a function of gate 2-source voltage; typical values.





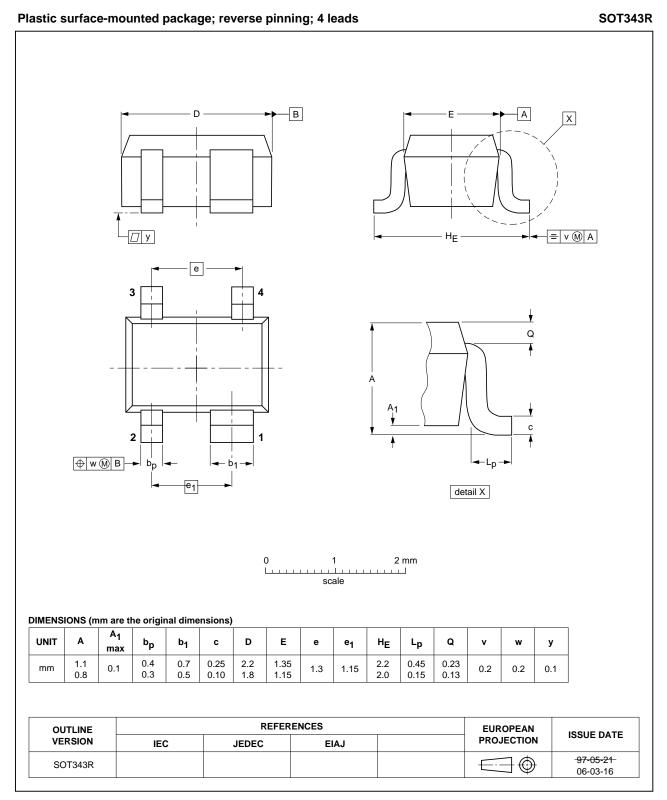




BF998WR

# N-channel dual-gate MOS-FET

#### PACKAGE OUTLINE



#### BF998WR

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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